Kingbright

2.15X1.7mm SMD LED WITH CERAMIC SUBSTRATE

Part Number: KT-2117SY9Z4S

Super Bright Yellow

ATTENTION
OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
DISCHARGE
SENSITIVE
DEVICES

Features

- Dimension: 2.15mmX 1.7mm X 0.8mm.
- Low thermal resistance.
- Ceramic package with silicone resin.
- Small package with high efficiency.
- Surface mount technology.
- ESD protection.
- Package : 2000pcs / reel.
- Moisture sensitivity level : level 2a.
- Soldering methods: IR reflow soldering.
- RoHS compliant.

Application Note

Static electricity and surge damage the LEDs.

It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs.

All devices, equipment and machinery must be electrically grounded.

Typical Applications

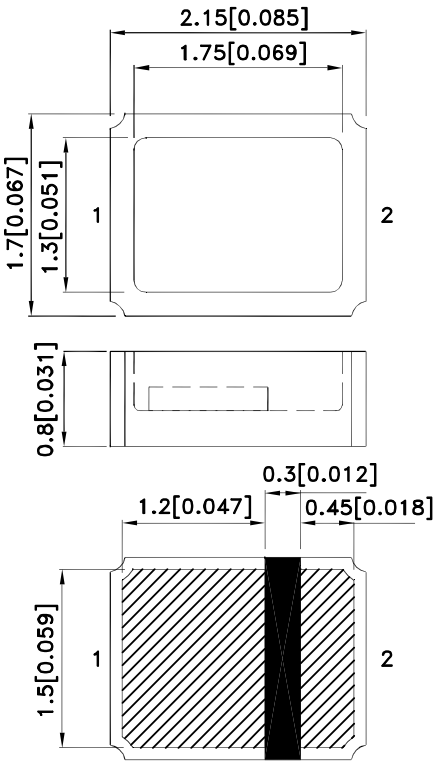
Room lighting

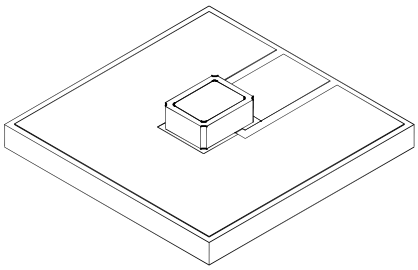
Architectural lighting

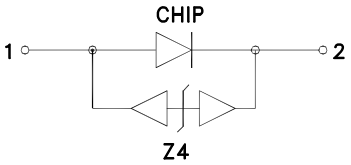
Decorative/pathway lighting

Front panel backlight

Package Dimensions







Notes:
1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.25(0.01") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.

Absolute Maximum Ratings at T_A=25°C

Parameter	Symbol	Value	Unit
Operating Temperature	Top	-40 To +100	°C
Storage Temperature	Tstg	-40 To +120	°C
Junction temperature[1]	T_J	120	°C
DC Forward Current [1]	I_F	350	mA
Peak Forward Current [2]	I_{FM}	500	mA
Reverse Voltage	V_R	5	V
Power dissipation	P_D	0.98	W
Electrostatic Discharge Threshold (HBM)		8000	V
Thermal resistance [1] (Junction/ambient)	$R_{th\ j\text{-}a}$	105	°C/W
Thermal resistance [1] (Junction/solder point)	$R_{th\ j\text{-}s}$	31	°C/W

Notes:
1. Results from mounting on metal core PCB,mounted on pc board-metal core PCB is recommend.for lowest thermal resistance.
2. 1/10 Duty Cycle, 0.1ms Pulse Width.

Electrical / Optical Characteristics at T_A=25°C

Parameter	Symbol	Value	Unit
Wavelength at peak emission I_F=350mA [Typ.]	λ peak	594	nm
Dominant Wavelength I_F=350mA [Typ.]	λ dom [1]	591	nm
Spectral Line Half-width I_F=350mA [Typ.]	$\Delta\lambda$	23	nm
Forward Voltage I_F = 350mA [Min.]	V_F [2]	1.8	V
Forward Voltage I_F = 350mA [Typ.]		2.3	
Forward Voltage I_F = 350mA [Max.]		2.8	
Allowable Reverse Current [Max.]	I_R	85	mA
Optical efficiency	η_{opt}	21.12	lm/W
Temperature coefficient of λ peak I_F=350mA, -10° C≤ T≤100° C [Typ.]	TC λ peak	0.12	nm/° C
Temperature coefficient of λ dom I_F=350mA, -10° C≤ T≤100° C [Typ.]	TC λ dom	0.07	nm/° C
Temperature coefficient of V_F I_F=350mA, -10° C≤ T≤100° C [Typ.]	TC_V	-3.0	mV/° C

Notes:
1.Wavelength is measured with a current pulse of 20ms at a tolerance of ±1nm.
2.Forward voltage is measured with a current pulse of 10ms at a tolerance of ±0.1V.
3.Wavelength value is traceable to the CIE127-2007 compliant national standards.

Selection Guide

Part No.	Dice	Lens Type	Luminous Intensity [2] Iv(cd)@ 350mA*		Φv (lm) [3] @ 350mA	Viewing Angle [1]
			Min.	Typ.	Typ.	2 θ 1/2
KT-2117SY9Z4S	Super Bright Yellow (AlGaInP)	Water Clear	3.1	4.5	17	120 °

Brightness codes

luminous Intensity [2] Iv(cd) @ 350mA			Φv (lm) [3] @ 350mA
Code.	Min.	Max.	Typ.
ZA	3.1	3.6	12
ZB	3.6	4.2	16
ZC	4.2	5	20
ZD	5	6	24

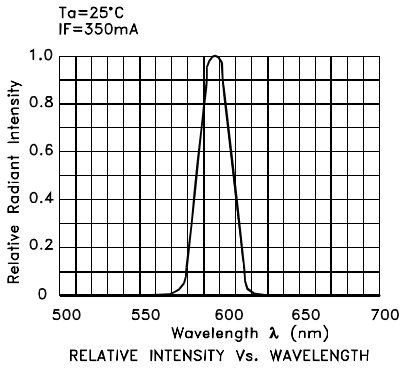
Notes:
1.θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2.Luminous intensity is measured by a current pulse of 10ms at a tolerance of ±15%,*LEDs are binned according to their luminous intensity.
3.The typical data of Luminous Flux can only reflect statistical figures, actual parameters of individual product could differ from the typical data.
For the purpose of product enhancement, the typical data is subject to change without prior notice.
Shipment may contain more than one of the light intensity groups.
Orders for single light intensity group are generally not accepted.
4.Luminous Intensity/Luminous Flux value is traceable to the CIE127-2007 compliant national standards.

Wavelength Groups

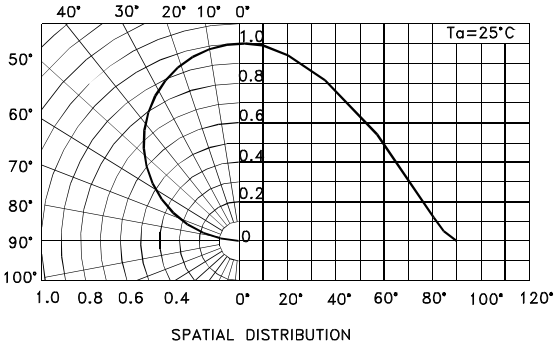
Wavelength			Unit
Code.	Min.	Max.	
2	584	586	nm
3	586	588	nm
4	588	590	nm
5	590	592	nm
6	592	594	nm
7	594	597	nm

Note:
Wavelength is measured with a current pulse of 20ms at a tolerance of ±1nm.
Shipment may contain more than one of the wavelength groups.
Orders for single wavelength group are generally not accepted.

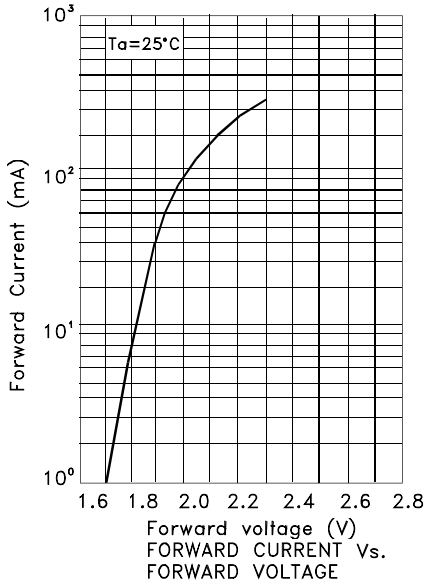
KT-2117SY9Z4S



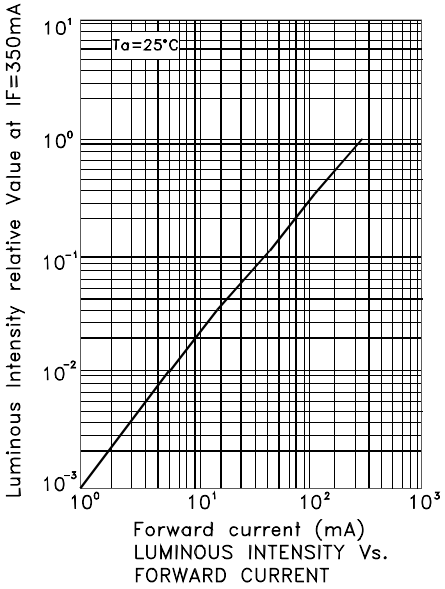
RELATIVE INTENSITY Vs. WAVELENGTH



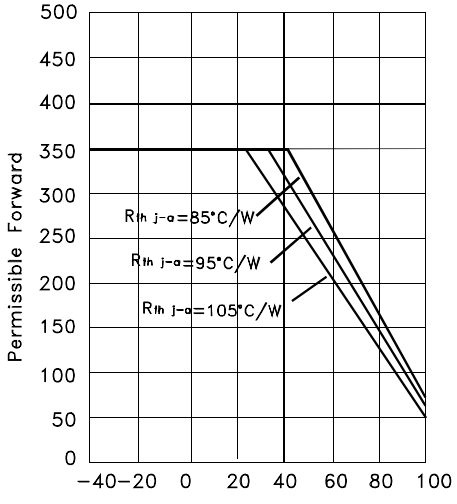
SPATIAL DISTRIBUTION



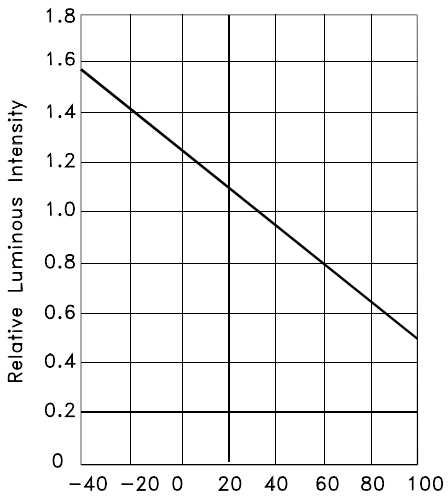
FORWARD CURRENT Vs.
FORWARD VOLTAGE



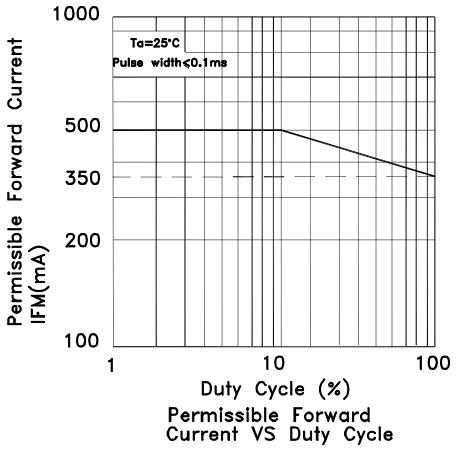
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



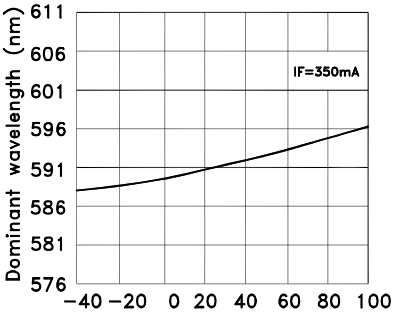
FORWARD CURRENT
DERATING CURVE



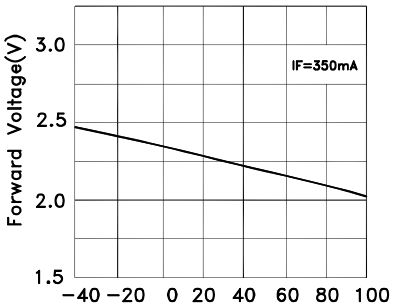
LUMINOUS INTENSITY VS.
AMBIENT TEMPERATURE



Permissible Forward
Current VS Duty Cycle



DOMINANT WAVELENGTH
VS AMBIENT TEMPERATRE

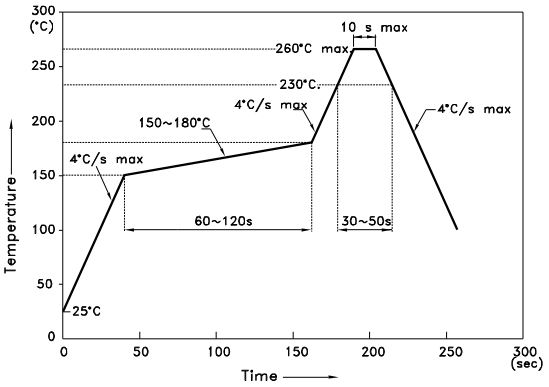


FORWARD VOLTAGE VS
AMBIENT TEMPERATRE

KT-2117SY9Z4S

Reflow soldering is recommended and the soldering profile is shown below.
Other soldering methods are not recommended as they might cause damage to the product.

Reflow Soldering Profile For Lead-free SMT Process.



NOTES:
1.We recommend the reflow temperature 245°C(+/-5°C).The maximum soldering temperature should be limited to 260°C.
2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
3.Number of reflow process shall be 2 times or less.

Heat Generation:

1.Thermal design of the end product is of paramount importance. Please consider the heat generation of the LED when making the system design. The coefficient of temperature increase per input electric power is affected by the thermal resistance of the circuit board and density of LED placement on the board ,as well as other components. It is necessary to avoid intense heat generation and operate within the maximum ratings given in this specification.

2.Please determine the operating current with consideration of the ambient temperature local to the LED and refer to the plot of Permissible Forward current vs. Ambient temperature on CHARACTERISTICS in this specification. Please also take measures to remove heat from the area near the LED to improve the operational characteristics on the LED.

3.The equation ① indicates correlation between T_j and T_a ,and the equation ② indicates correlation between T_j and Ts

$T_j = T_a + R_{thj\text{-}a} * W$ ..... ①

$T_j = T_s + R_{thj\text{-}s} * W$ ..... ②

Tj = dice junction temperature: °C

Ta = ambient temperature:°C

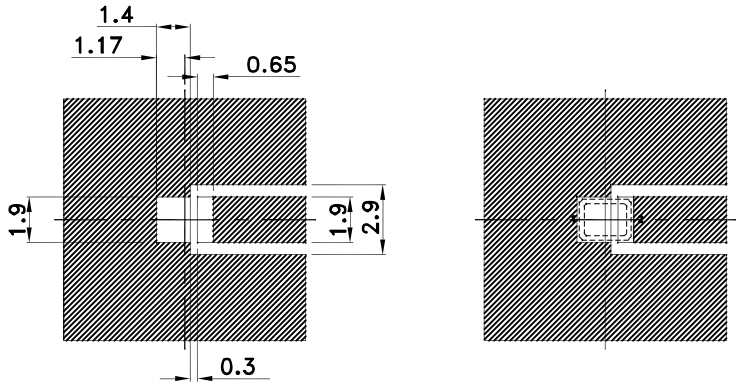
Ts = solder point temperature:°C

$R_{thj\text{-}a}$ = heat resistance from dice junction temperature to ambient temperature : °C / W

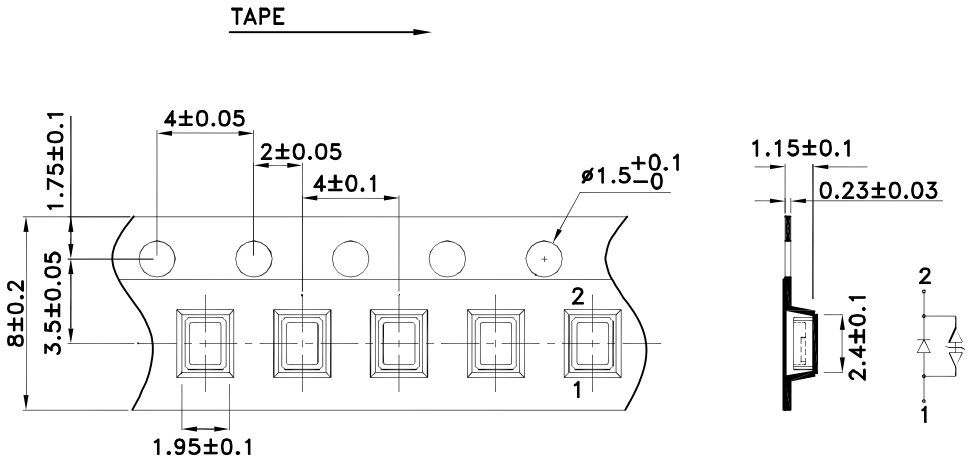
$R_{thj\text{-}s}$ = heat resistance from dice junction temperature to Ts measuring point : °C / W

W = inputting power (IFx VF) : W

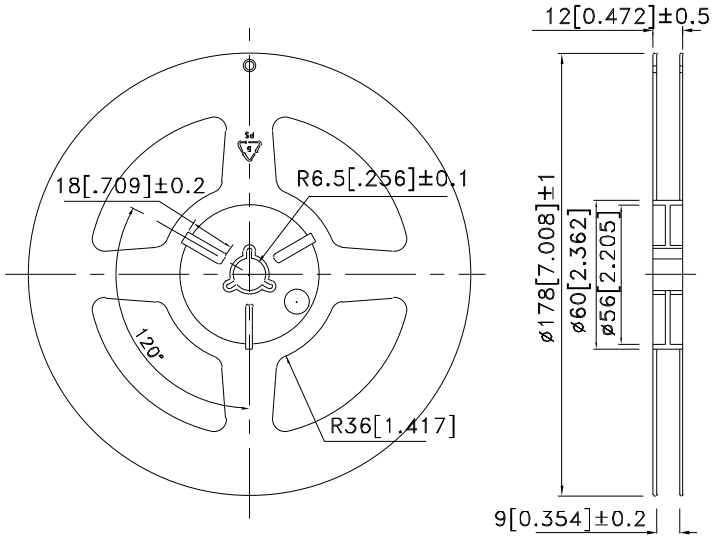
Recommended Soldering Pattern
(Units : mm; Tolerance: ± 0.1)



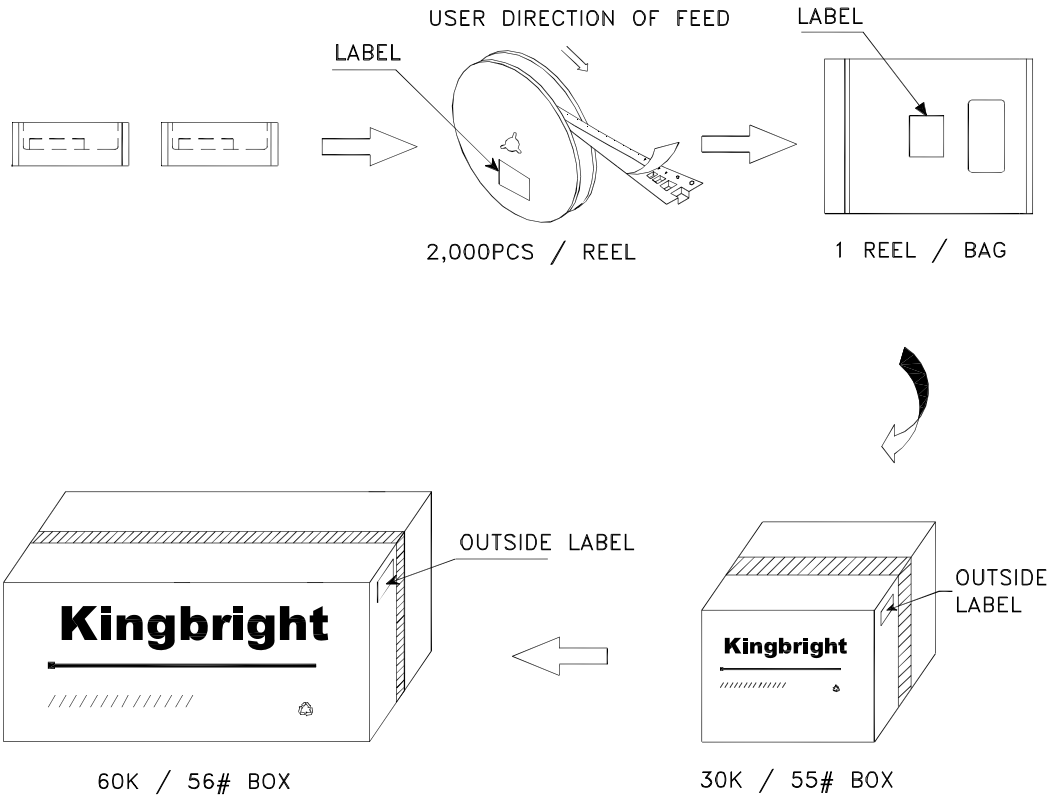
Tape Specifications (Units : mm)

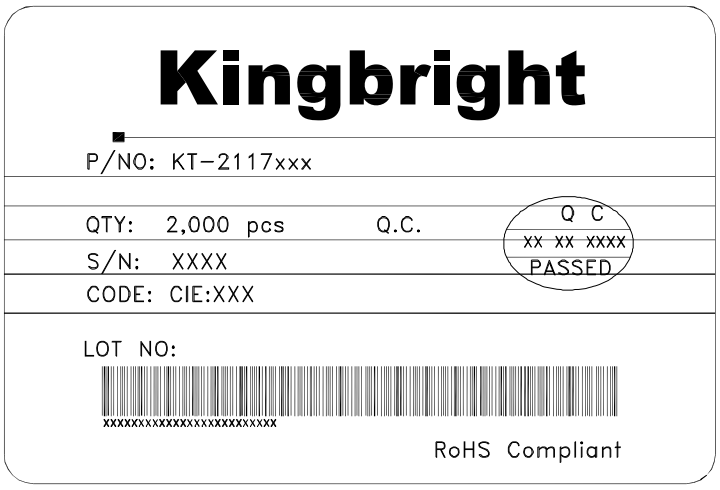


Reel Dimension



PACKING & LABEL SPECIFICATIONS **KT-2117SY9Z4S**

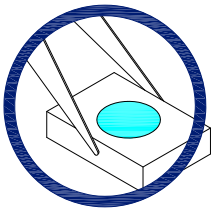




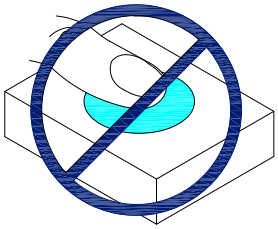
Handling Precautions

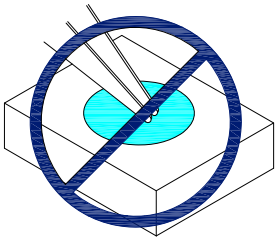
Compare to epoxy encapsulant that is hard and brittle, silicone is softer and flexible. Although its characteristic significantly reduces thermal stress, it is more susceptible to damage by external mechanical force.
As a result, special handling precautions need to be observed during assembly using silicone encapsulated LED products. Failure to comply might lead to damage and premature failure of the LED.

1. Handle the component along the side surfaces by using forceps or appropriate tools.

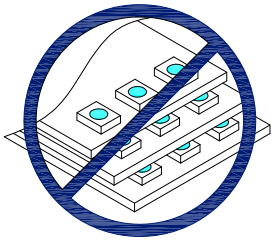


2. Do not directly touch or handle the silicone lens surface. It may damage the internal circuitry.

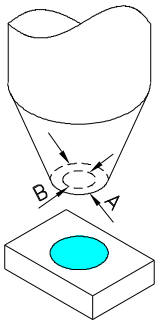




3. Do not stack together assembled PCBs containing exposed LEDs. Impact may scratch the silicone lens or damage the internal circuitry.



4.1. The inner diameter of the SMD pickup nozzle should not exceed the size of the LED to prevent air leaks.
4.2. A pliable material is suggested for the nozzle tip to avoid scratching or damaging the LED surface during pickup.
4.3. The dimensions of the component must be accurately programmed in the pick-and-place machine to insure precise pickup and avoid damage during production.



5. As silicone encapsulation is permeable to gases, some corrosive substances such as H_2S might corrode silver plating of leadframe. Special care should be taken if an LED with silicone encapsulation is to be used near such substances.